

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	83	(epi\$6 contact) WITH (HBT (heterojunction adj bipolar)) WITH (FET (field adj effect))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/19 18:26
S2	9	("5250826").URPN.	USPAT	OR	ON	2005/07/19 17:19
S3	9	("5250826").URPN.	USPAT	OR	ON	2005/07/19 17:23
S4	3	("4821090" "5027170" "5068756").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/07/19 17:24
S5	13	("5243207").URPN.	USPAT	OR	ON	2005/07/19 17:35
S6	1	("5068756").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/07/19 17:36
S7	4	("4821090" "4830980" "4929570" "5012318").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/07/19 17:38
S8	27	("5077231").URPN.	USPAT	OR	ON	2005/07/19 17:42
S9	2179	(HBT (heterojunction adj bipolar)) AND (FET (field adj effect))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 07:41
S10	24	S9 AND (contact with cap with (subcollector (sub near collector)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/19 18:15
S11	76	S9 AND (contact with (common shar\$3))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/19 18:27
S12	0	S9 AND ((first near epi\$6) WITH (FET MOS MOSFET))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/19 18:22
S13	5	S9 AND ((first near epi\$6) WITH (second near epi\$6) WITH (third near epi\$6))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/19 18:24

S14	500	((first near epi\$6) AND (second near epi\$6) AND (third near epi\$6))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 08:19
S15	0	S14 and ((second near (epi\$6 contact)) WITH (HBT (heterojunction adj bipolar)) WITH (FET (field adj effect)))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/19 18:31
S16	189	S14 AND (common shar\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/19 18:27
S17	2164	(HBT (heterojunction adj bipolar)) AND (FET (field adj effect adj transistor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/19 18:30
S18	10	S14 and S9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/19 18:31
S19	111	BiFET AND (HBT (heterojunction adj bipolar) bipolar) AND (FET (field adj effect adj transistor\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 08:08
S20	273	epi\$6 WITH (HBT (heterojunction adj bipolar) bipolar) WITH (FET (field adj effect adj transistor\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 07:56
S21	30230	(HBT (heterojunction adj bipolar) bipolar) AND (FET (field adj effect adj transistor\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 08:09
S22	118	S21 AND ((second near epi\$6) WITH (first near epi\$6))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 08:33

S23	500	(first near epi\$6) AND (second near epi\$6) AND (third near epi\$6)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 08:20
S24	40	S23 AND ((second near epi\$6) NEAR5 (top over) NEAR (second near epi\$6))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 08:25
S25	38	S23 AND S21	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 08:25
S26	0	S21 AND (isolat\$3 with (He near ion near implant\$5))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 08:35
S27	0	S21 AND (isolat\$3 same (He near ion near implant\$5))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 08:34
S28	4	S21 AND (isolat\$3 with ((Helium He) near ion near implant\$5))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 08:39
S29	9	(isolat\$3 with ((Helium He) near ion near implant\$5))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/07/20 08:39